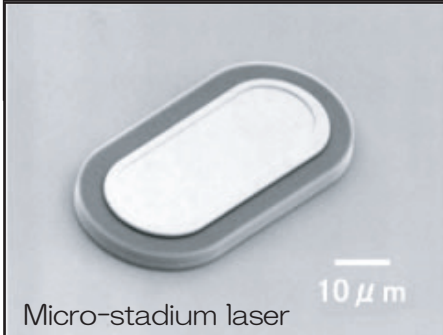


Semiconductor Process Service

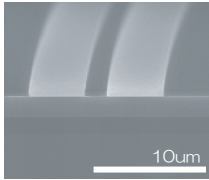
We're your problem solving partner!

NTT-AT give you "total tech support" for your prototyping of semiconductor devices, so we are the outsourcing partner you can rely on for semiconductor process development.

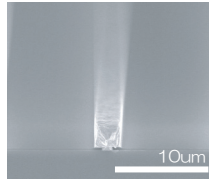


Micro-stadium laser

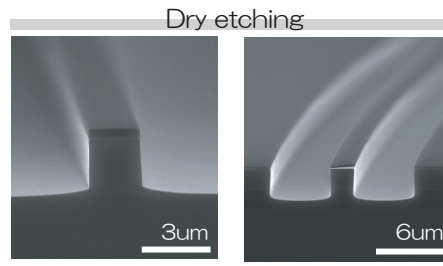
Insulating film patterning Metal patterning



Etching mask for waveguide

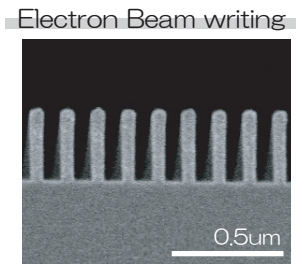


Au plating electrode



InP

GaAs



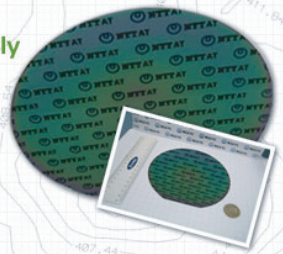
EB resist

GaN Epitaxial Wafers

Bringing environmentally friendly GaN power devices to reality.

GaN Epitaxial Wafer

- GaN epitaxial wafer on 6 inch Si substrate -



Able to provide various kinds of substrate

| Si | Sapphire | SiC | GaN |
|------|----------|------|-----|
| 2-6" | 2-4" | 2-4" | 2" |

Very flexible to meet wide range of required quantity

- Small quantity for prototype production
- Larger quantity for mass production needs

Mass production needs are supported by our partnership with Mitsubishi Chemical corporation.

HEMT structure is grown by MOCVD method.

For more information, please contact

NTT Advanced Technology Corporation

International Business Division

E-Mail : moreinfo@ntt-at.com

URL : <http://www.ntt-at.com>